

N-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- Surface-mounted package
 Super Trench
- Advanced trench cell design
 MSL1

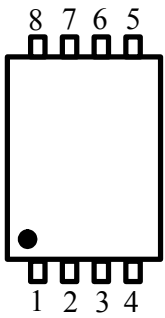
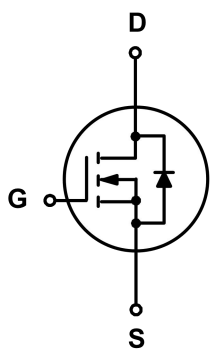
1.2 Applications

- LCD TV appliances
 LCDM appliances
- High power inverter system

1.3 Quick reference

- $BV \cong 120\text{ V}$
 $P_{tot} \cong 156\text{ W}$
 $I_D \cong 100\text{ A}$
- $R_{DS(ON)} \leq 5.5\text{ m}\Omega @ V_{GS} = 10\text{ V}$
 $R_{DS(ON)} \leq 7.5\text{ m}\Omega @ V_{GS} = 4.5\text{ V}$

2. Pin Description

Pin	Description	Simplified Outline	Symbol
1,2,3	Source	 Top View PDFN5x6-8L	
4	Gate		
5,6,7,8	Drain		

3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	Drain-Source Voltage	$T_C = 25\text{ }^\circ\text{C}$	120	-	V
V_{GS}	Gate-Source Voltage	$T_C = 25\text{ }^\circ\text{C}$	-	± 20	V
I_D^*	Drain Current (DC)	$T_C = 25\text{ }^\circ\text{C}, V_{GS} = 10\text{ V}$	-	100	A
		$T_C = 100\text{ }^\circ\text{C}, V_{GS} = 10\text{ V}$	-	67	A
$I_{DM}^{***,***}$	Drain Current (Pulsed)	$T_C = 25\text{ }^\circ\text{C}, V_{GS} = 10\text{ V}$	-	240	A
P_{tot}^*	Drain power dissipation	$T_C = 25\text{ }^\circ\text{C}$	-	156	W
T_{stg}	Storage Temperature		-55	150	$^\circ\text{C}$
T_J	Junction Temperature		-	150	$^\circ\text{C}$
I_S	Continuous-Source Current	$T_C = 25\text{ }^\circ\text{C}$	-	100	A
E_{AS}^*	Single Pulsed Avalanche Energy	$V_{DD} = 50\text{ V}, L = 1\text{ mH}$	-	560	mJ
$R_{\theta JA}^*$	Thermal Resistance- Junction to Ambient		-	62.5	$^\circ\text{C/W}$
$R_{\theta JC}^*$	Thermal Resistance- Junction to Case		-	0.8	

Notes :

- * Surface Mounted on 1 in² pad area, $t \leq 10\text{ sec}$
- ** Pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
- *** Limited by bonding wire

4. Marking Information

Product Name	Marking
KJ0512G	<div style="display: inline-block; border: 1px solid black; padding: 2px;"> 0512 YWWXXX </div> YWW: Date Code

5. Ordering Code

Product Name	Package	Reel Size	Tape width	Quantity	Note
KJ0512G	PDFN5*6			5000	

Note: KUAJIEXIN defines " Green " as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC / JEDEC J-STD-020C)

6. Electrical Characteristics ($T_A=25^\circ$ Unless Otherwise Noted)

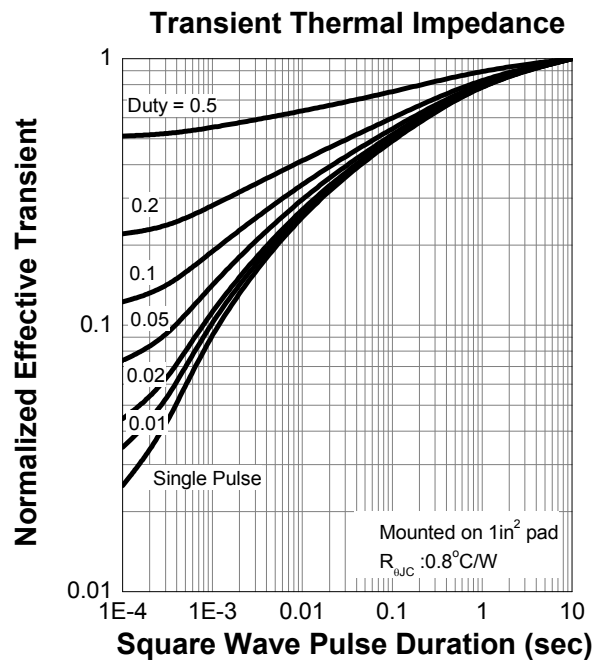
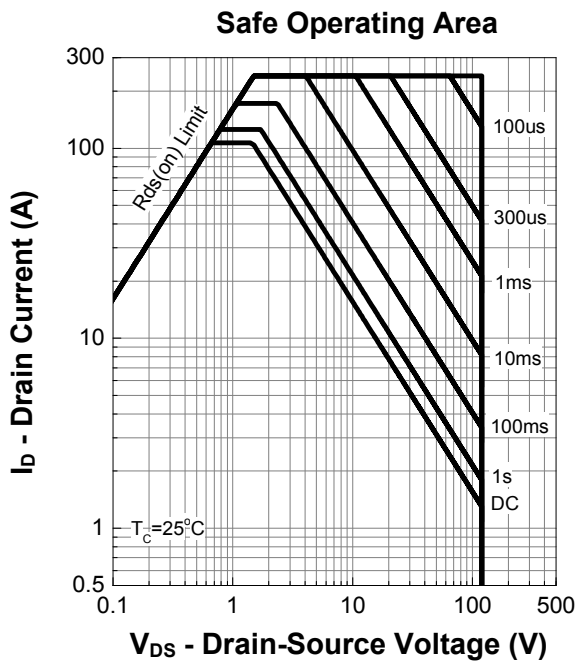
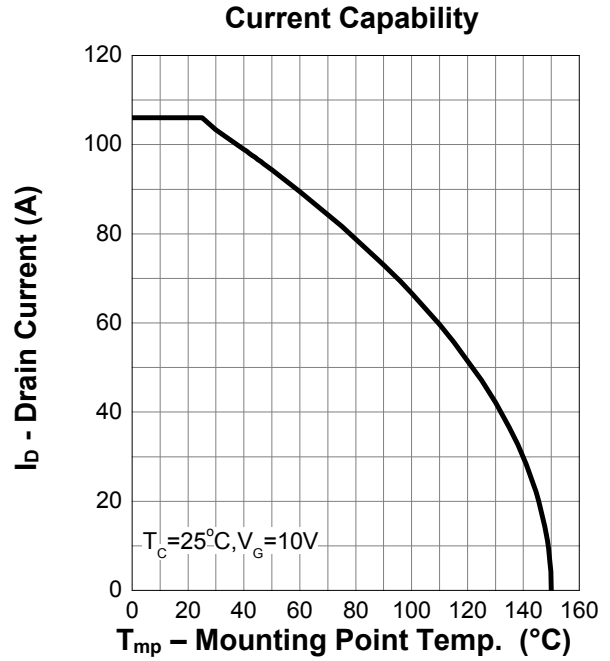
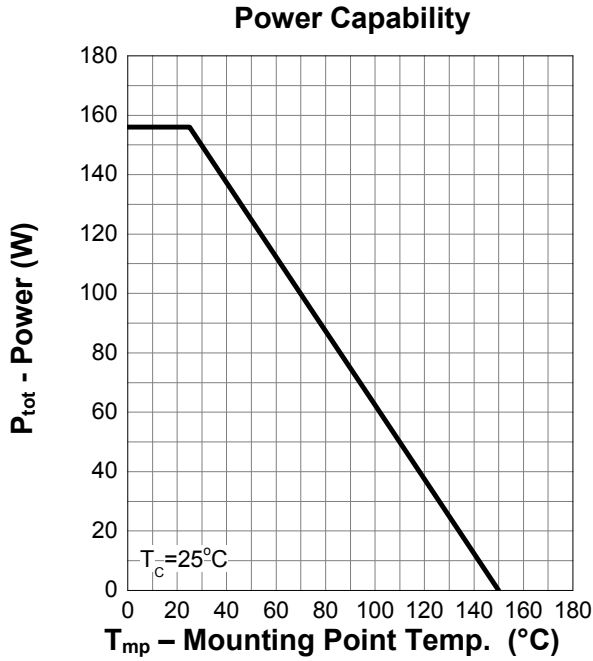
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_{DS} = 250\ \mu\text{A}$	120	-	-	V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = 250\ \mu\text{A}$	1	-	3	V
I_{DSS}	Drain Leakage Current	$V_{DS} = 96\text{ V}, V_{GS} = 0\text{ V}$ $T_J = 85^\circ\text{C}$	-	-	1	μA
			-	-	30	μA
I_{GSS}	Gate Leakage Current	$V_{GS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$	-	-	± 100	nA
$R_{DS(ON)}^a$	On-State Resistance	$V_{GS} = 10\text{ V}, I_{DS} = 30\text{ A}$	-	4.5	5.5	m Ω
		$V_{GS} = 4.5\text{ V}, I_{DS} = 20\text{ A}$	-	5.5	7.5	
Diode Characteristics						
V_{SD}^a	Diode Forward Voltage	$I_{SD} = 30\text{ A}, V_{GS} = 0\text{ V}$	-	-	1.3	V
t_{rr}	Reverse Recovery Time	$I_{DS} = 30\text{ A}, di_{SD}/dt = 100\text{ A}/\mu\text{s}$	-	94	-	nS
Q_{rr}	Reverse Recovery Charge		-	299	-	nC
Dynamic Characteristics^b						
C_{iss}	Input Capacitance	$V_{GS} = 0\text{ V}, V_{DS} = 60\text{ V}$ Frequency = 1 MHz	-	4247	-	pF
C_{oss}	Output Capacitance		-	567	-	
C_{riss}	Reverse Transfer Capacitance		-	38	-	
$t_d(on)$	Turn-on Delay Time	$V_{DS} = 60\text{ V}, V_{GEN} = 10\text{ V},$ $R_G = 4.5\ \Omega, R_L = 2\ \Omega,$ $I_{DS} = 30\text{ A}$	-	14	-	nS
t_r	Turn-on Rise Time		-	51	-	
$t_d(off)$	Turn-off Delay Time		-	67	-	
t_f	Turn-off Fall Time		-	110	-	
Gate Charge Characteristics^b						
Q_g	Total Gate Charge	$V_{DS} = 60\text{ V}, V_{GS} = 10\text{ V},$ $I_{DS} = 30\text{ A}$	-	77	-	nC
Q_{gs}	Gate-Source Charge		-	16	-	
Q_{gd}	Gate-Drain Charge		-	18	-	

Notes :

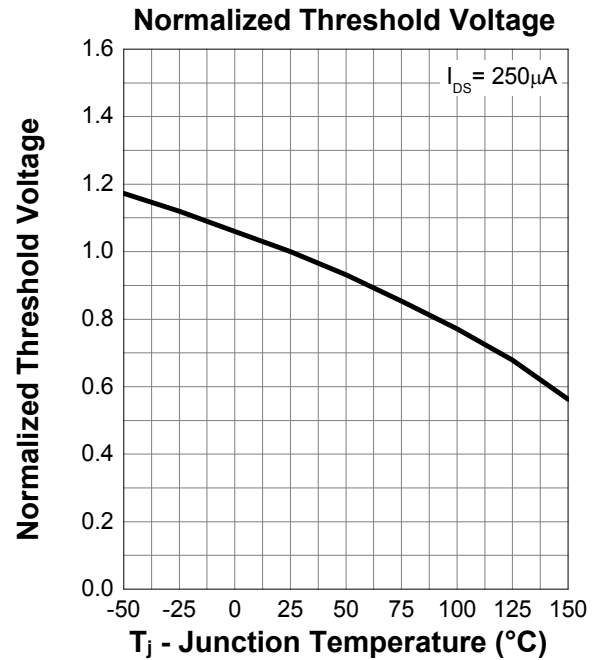
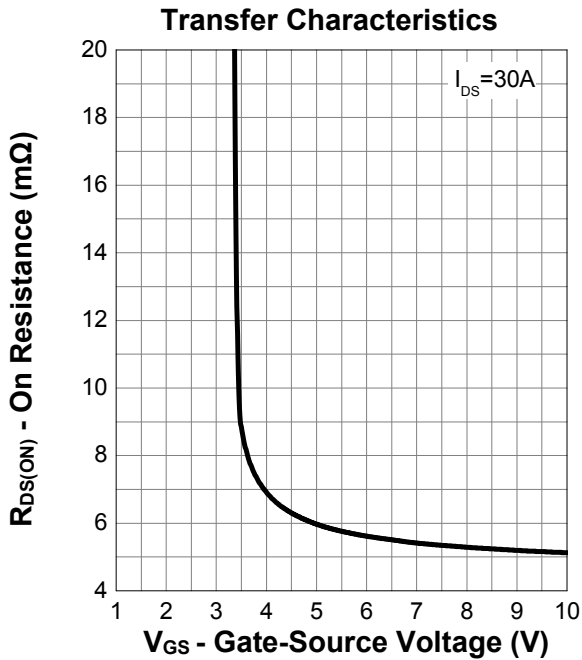
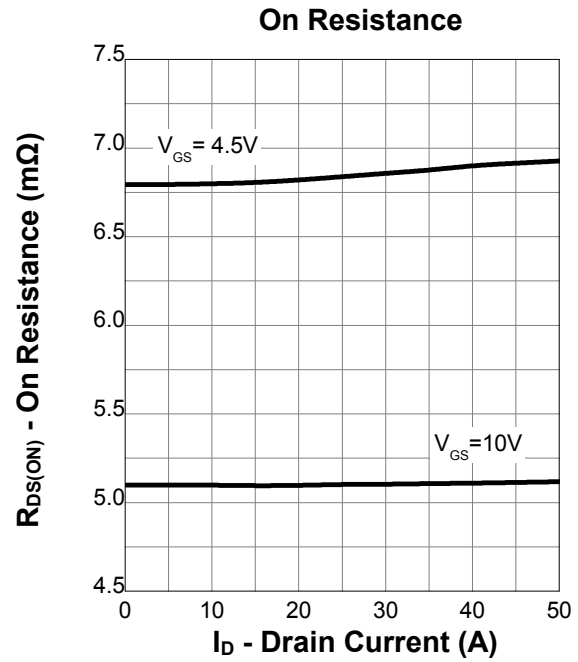
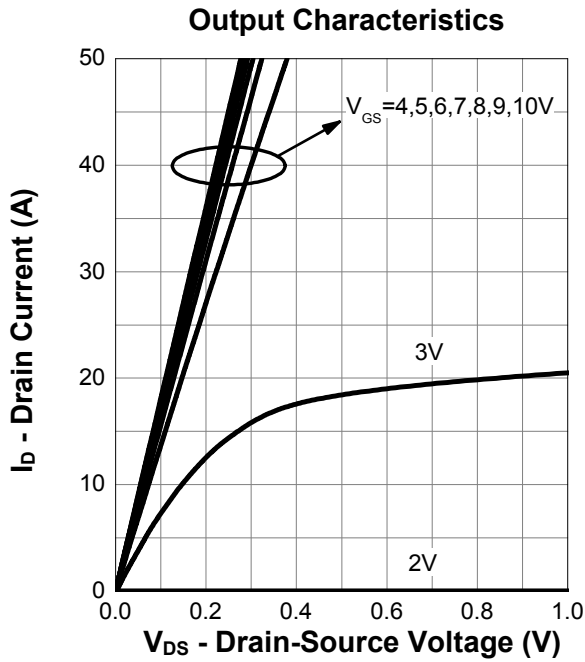
a : Pulse test ; pulse width $\leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$

b : Guaranteed by design, not subject to production testing

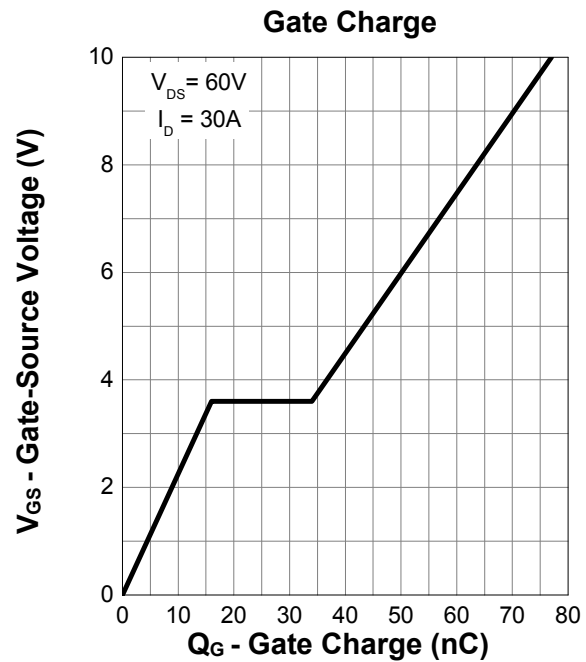
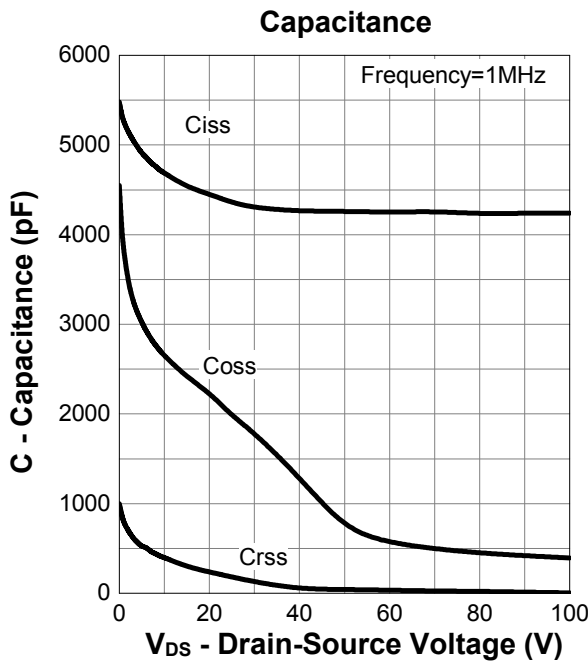
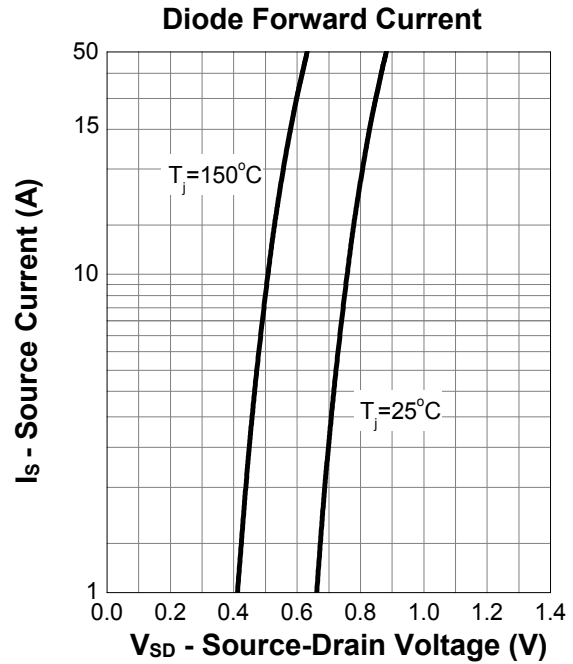
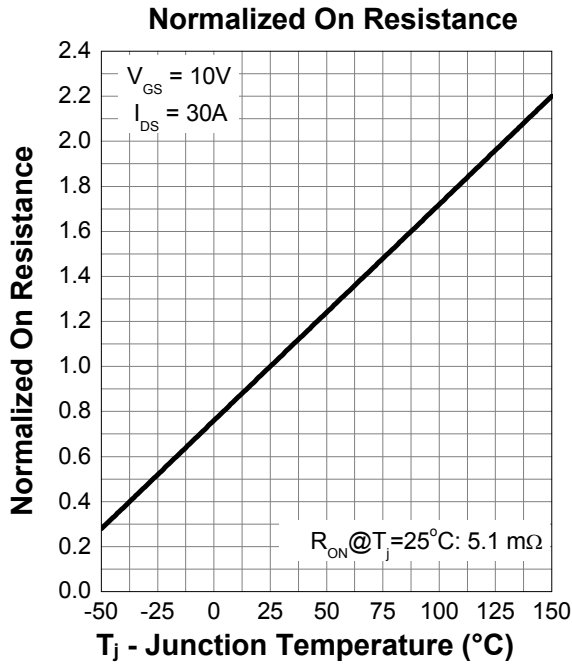
7. Typical Characteristics



7. Typical Characteristics (cont.)

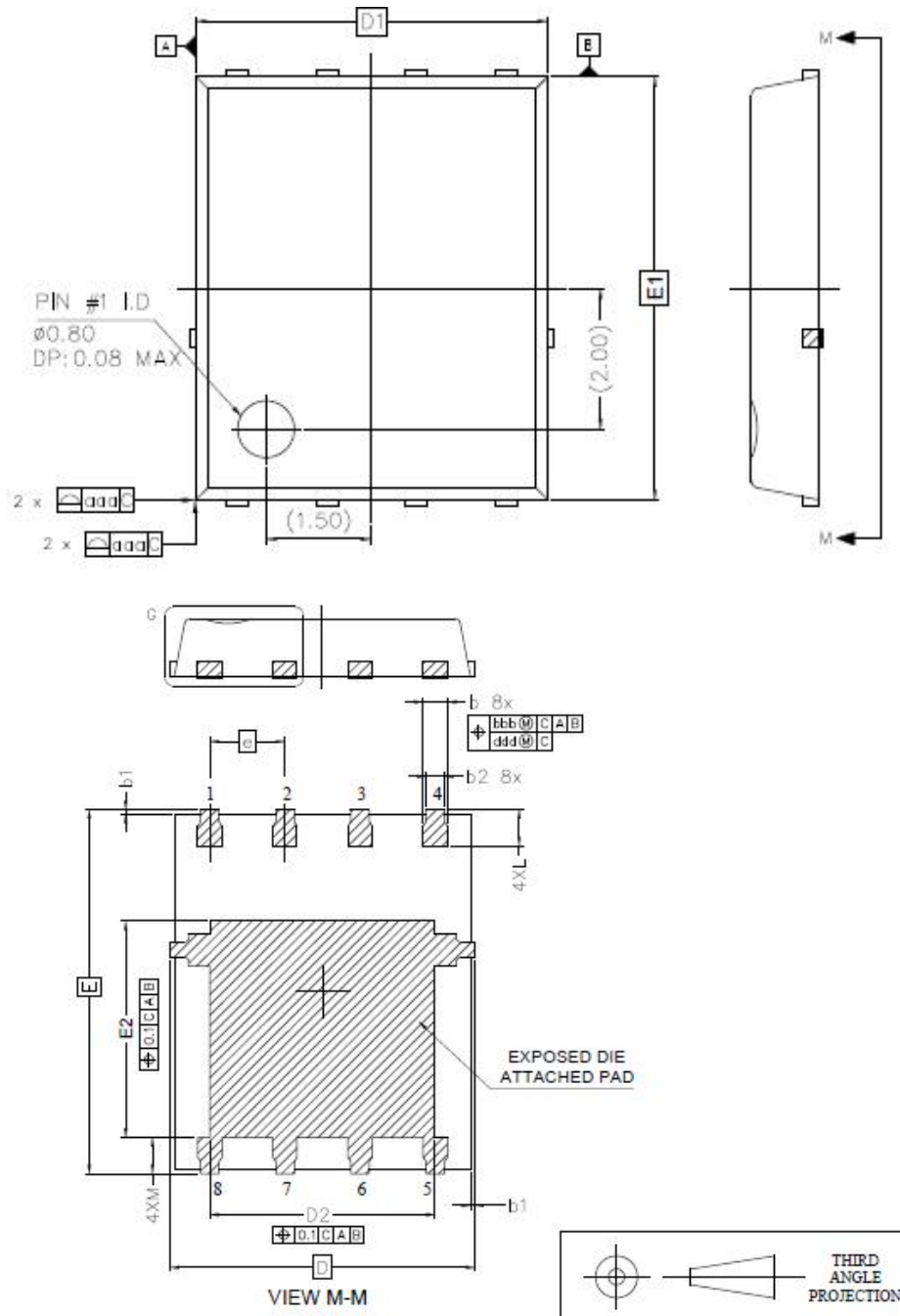


7. Typical Characteristics (cont.)



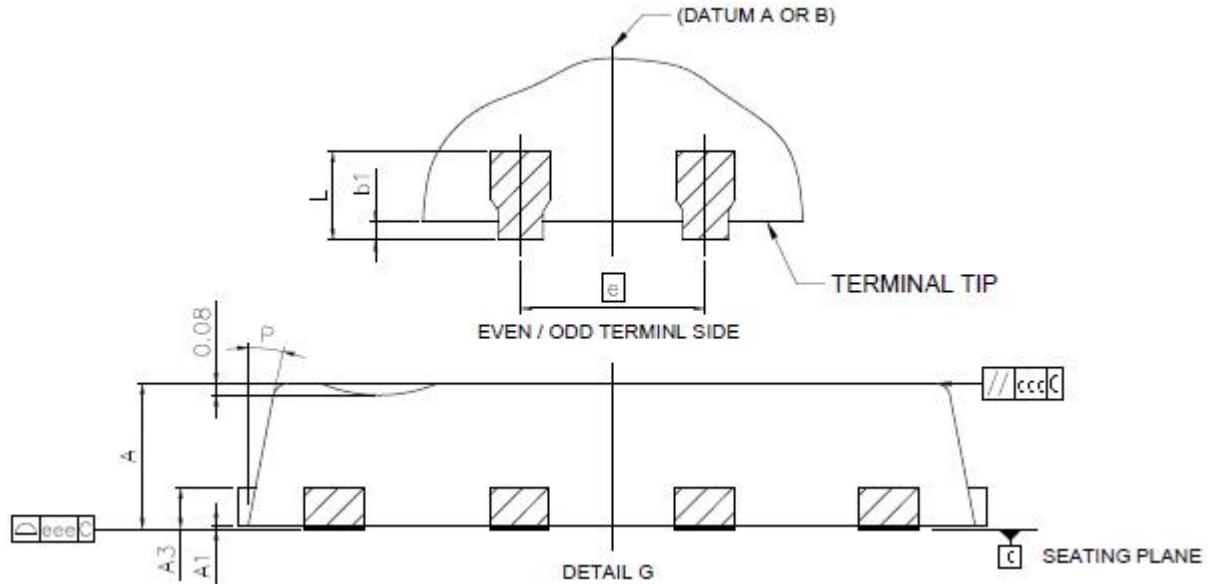
8. Package Dimensions

PDFN5x6 - 8L Package



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PDFN5x6 - 8L Package



SYMBOL	MIN	MAX	SYMBOL	MIN	MAX
A	0.95	1.05	aaa	0.10	
A1	0.00	0.05	bbb	0.10	
A3	0.25 REF		ccc	0.10	
b	0.31	0.51	ddd	0.05	
b1	0.03	0.13	eee	0.08	
b2	0.21	0.41			
D	5.15 BSC				
D1	5.00 BSC				
D2	3.70	3.90			
E	6.15 BSC				
E1	6.00 BSC				
E2	3.56	3.76			
e	1.27 BSC				
L	0.51	0.71			
M	0.51	0.71			
P	10°	12°			